# **DT12T Standard Series TRIACs**



#### DT12T Standard Series TRIACs SILICON BIDIRECTIONAL THYRISTORS

#### **General description** These products 12A TRAIC are packages for third quadrant, DT12T are high commutation performance

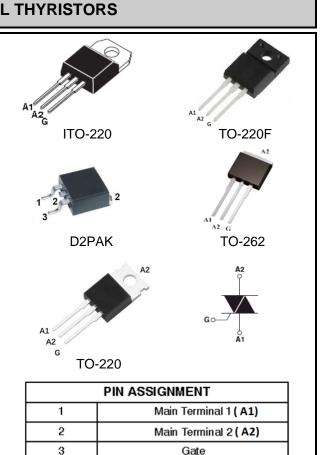
quadrant, D1121 are high commutation performance without snubber circuit. It can be controlled by phase angle trigger or on/off trigger.

#### FEATURES

- · Passivated die for reliability and uniformity
- Three-quadrant triggering.
- Over 800V VDRM/VRRM
- 125 Degree C operation temperature.
- Without snubber circuit.
- "Green" molding compound,
- UL flammability classification 94V-0, (No Br. Sb. Cl)
- Lead free in RoHS II 2015/863/EU compliant
- Moisture sensitivity meets industry standard IPC/JEDEC J-STD-020'

#### APPLICATIONS

- General purpose AC switch control
- Control loads in Motor, Fan, and Pump.
- Solenoid drivers
- LED Dimming
- Inrush current limiting circuits



## **DT12T Standard Series TRIACs**

ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise specified.)

## **Absolute Ratings**

PARAMETER	SYMBOL	VALUE	UNIT				
Peak repetitive off-state voltage ( Tj = -40 to 125°C, Full sine wave, 50 to 60 Hz; Gate open) (Note 1)	V <sub>drm</sub> V <sub>rrm</sub>	800	V				
On-stage RMS current (Full sine wave, $T_C = 100^{\circ}C$ )	I <sub>T(RMS)</sub>	12	А				
Peak non-repetitive surge current ( one full cycle 60 Hz, Tj = $25^{\circ}$ C)	Ітѕм	100	А				
Circuit fusing consideration ( $t = 8.3ms$ )	I <sup>2</sup> T	41.5	A <sup>2</sup> S				
Operating junction temperature range	Tj	-40 to +125	°C				
Storage temperature range	Тѕтс	-40 to +150	°C				
Note :	lote :						

(1)  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous basis.

Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



## **Thermal Characteristics**

PARAMETER	SYMBOL		VALUE	UNIT
Thermal resistance from junction to case, without heatsink, (1)	Rth(j-c)	Max	12	°C/W
Junction to ambient, without heatsink, (1)	Rth(j-a)	Тур	35	C/vv
Maximum lead temperature for soldering purposes (1/8" form case for 10 seconds)	TL	Max	260	°C

Note1: without heatsink, unidirectional, continuous & full cycle.

## **Static Characteristics**

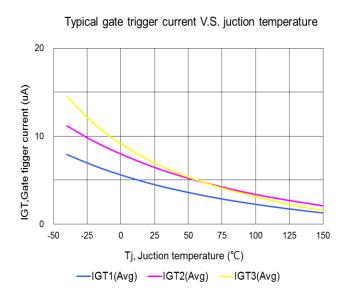
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Threshold Voltage (Tj = 125°C)	V <sub>to</sub>			0.95	V	
Dynamic resistors (Tj = 125°C)	R₀			30	mΩ	
Peak repetitive forward or reverse blocking $Tj = 25^{\circ}C$					5	uA
current ( $V_{AK}$ = rated $V_{DRM}$ and $V_{RRM}$ , gate open)	Tj = 125°C	Irrm			0.5	mA

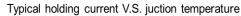
## **ON Characteristics**

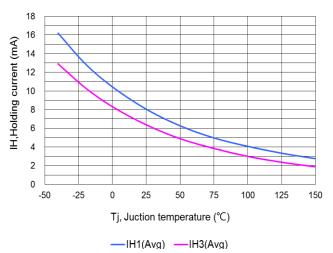
PARAMETER	SYMBOL	DT12T10	DT12T35		UNIT
Peak forward on-state voltage ( $I_{TM} = 12 \text{ A} @ \text{Tj} = 25^{\circ}\text{C}$ )	Vtm	1.5	1.5	Max	V
$V_{D}=V_{DRM}$ , $R_{L}=100\Omega$ , $Tj=125^{\circ}C$	$V_{GD}$	0.25	0.25	Min	V
Gate trigger current ( $V_{AK}$ = 12V, R <sub>L</sub> =100 $\Omega$ )	Igt1 Igt2 Igt3	10 10 10	35 35 35	Max	mA
Gate trigger voltage ( $V_{AK}$ = 12V, RL=100 $\Omega$ )	Vgt1 Vgt2 Vgt3	1	1	Max	V
Holding current ( VAK = 12V, $R_L$ =100 $\Omega$ )	Ін1 Ін3	10	50	Max	mA
Latching current ( $V_{AK}$ = 12V, $R_L$ =100 $\Omega$ )	I <sub>L1</sub> IL2 IL3	20 30 20	50 80 50	Max	mA
Critical rate of rise of on-state current, Tj = 125°C	dl/dt(s)	50	50	Max	A/us
VD = 67% VDRM, gate open, Tj = 125°C	dV/dt	500	3000	Max	V/us
Without snubber, Tj = 125°C	dl/dt(c)	2	8	Max	A/ms
125°C, Gate open, 10V/dt	di/dt(c)	10	40	Max	A/ms



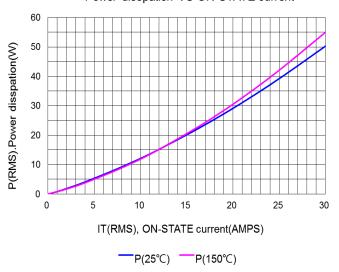
#### DT12T10 Characteristic

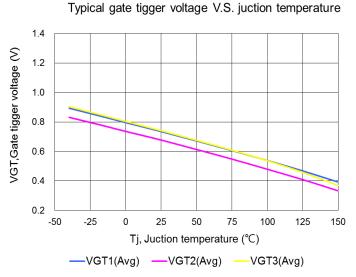




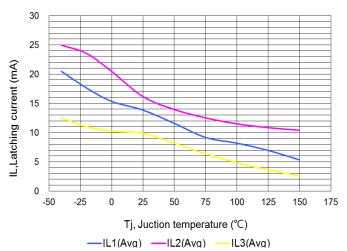


Power disspation VS ON-STATE current

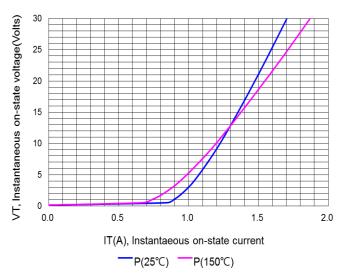




Typical latch current V.S. juction temperature

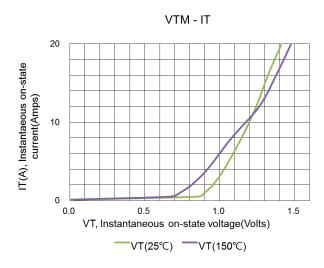


IT-VTM

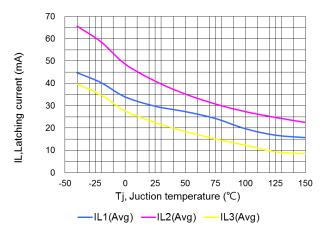




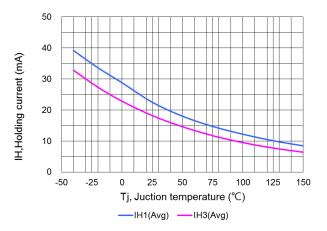
#### DT12T35 Characteristic

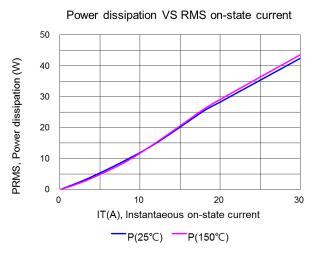


Typical latch current V.S. juction temperature

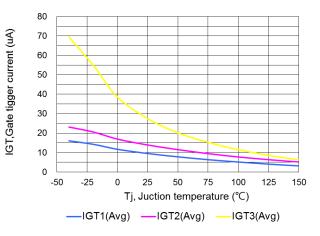


Typical holding current V.S. juction temperature

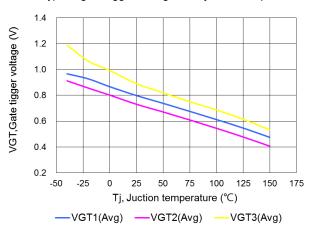




Typical gate trigger current V.S. juction temperature



Typical gate tigger voltage V.S. juction temperature





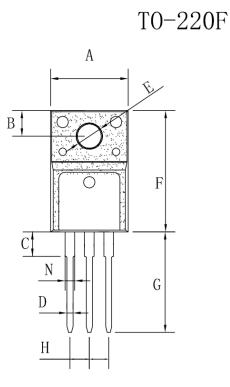
### Ordering information scheme

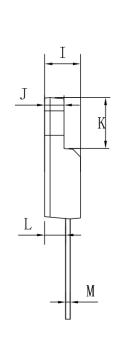
	<u>D T 16 T 35 F -BHX</u> ∆
Product Code IT Amp Code Quadrantal Code IGT&VCEsat Code Package Code Voltage Code Operation Temp. Code Internal Code1	e
Type Code: Product Code: IT Amp Code: Quadrantal Code: IGT&VCEsat Code: Package Code:	·
Voltage Code: Operation Temp Code:	A=> 600V, B=> 800V, C=> 1000V None=>125°C, H=>150°C



## **TO-220F Plastic Package**

PACKAGE OUTLINE DIMENSIONS

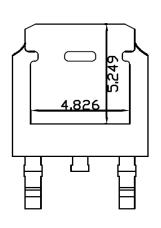


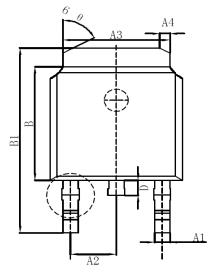


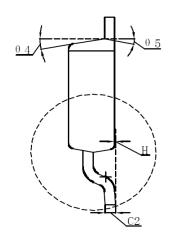
	Unit(	mm)	Unit	t(inch)
DIM.	Min	Max	Min	Max
Α	9.6	10.5	0.377	0. 413
В	3.15	3.65	0.124	0.143
С	2.95	3.5	0.116	0.137
D	0.7	0.92	0.027	0.036
Ε	3	3.4	0.118	0.133
F	15.3	16.5	0.602	0.649
G	12.85	13.45	0. 505	0. 529
Н	2.4	2.7	0.094	0.106
Ι	4.15	5.12	0.163	0.201
J	2.28	2.65	0. 089	0.104
К	6.12	6.95	0.240	0.273
L	2.45	2.9	0.096	0.114
Μ	0.5	0.6	0.019	0.023
Ν	1.18	1.42	0.046	0.055

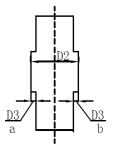


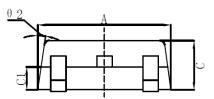
## DPAK(TO-252) Plastic Package

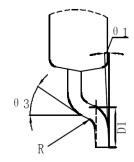










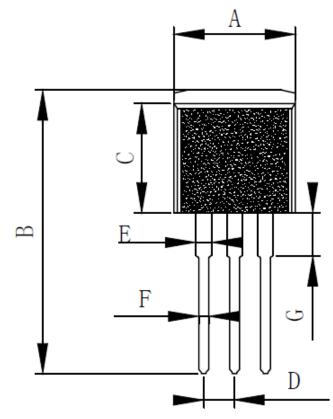


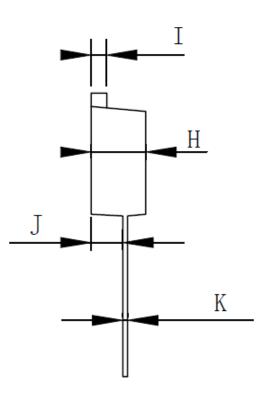
0≤a, b≤0.1

DIM	Millim	eters	DIM	Millim	eters	DIM	Millin	neters
DIN	Min	Max		Min	Max		Min	Max
Α	6.50	6.70	C1	0.967	1.087	θ1	0°~8°	
A1	0.71	0.81	C2	0.498	0.518	θ2	8.5 °TYP4	
A2	2.236	2.336	D	0.70	0.90	θ3	25 ° TYP	
A3	5.284	5.384	D1	1.40	1.60	θ4	10 ° TYP	
A4	0.75	0.85	D2	0.81	0.91	θ5	10 °	TYP
В	6.00	6.20	D3	0.05	TYP	θ6	70 ° TYP	
B1	9.80	10.10	Н	0.00	0.10			
С	2.20	2.40	R	0.40TYP				



### **TO-262 Plastic Package**

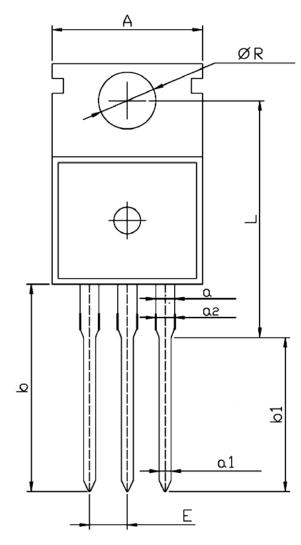


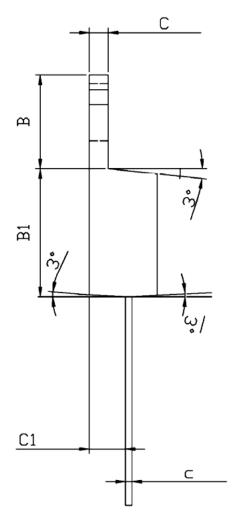


ltom	Unit: mm						
Item	Туре	Min	Max				
Α	10	9.95	10.2				
В	23.35	23.25	23.45				
С	9	8.9	9.1				
D	2.54	2.5	2.6				
E	1.27	1.2	1.35				
F	0.8	0.75	0.85				
G	3.5	3.3	3.6				
Н	4.5	4.45	4.55				
	1.27	1.25	1.29				
J	2.6	2.5	2.7				
K	0.4	0.38	0.42				



#### **TO-220C Plastic Package**

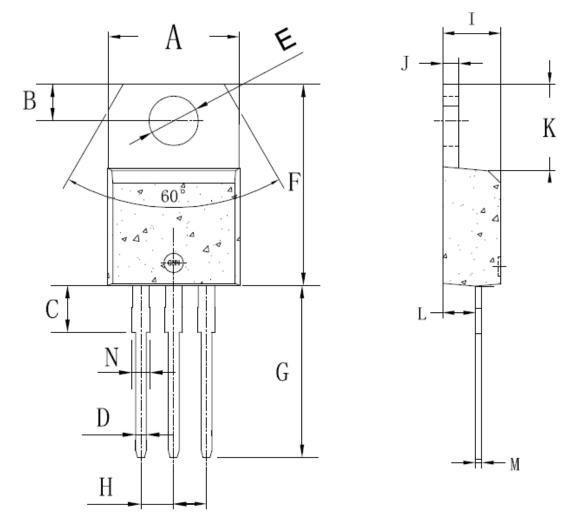




DIM	Millim	neters	DIM	Millin	neters	DIM	Millimeters	
	Min	Max		Min	Max		Min	Max
Α	9.7	10.4	а	1.22	1.32	a2	1.18	1.45
В	6.13	6.82	a1	0.7	0.92	C2	4.3	4.71
С	1.2	1.42	b1	9.6	10.6	E	2.34	2.74
B1	9.0	9.4	С	0.38	0.65	R	3.55	3.78
b	12.6	13.6	C1	2.2	2.75	L	15.7	16.14



## ITO-220 Plastic Package



DIM	Millim	neters	DIM	Millimeters DIM Millime		DIM	neters	
	Min	Max		Min	Max	DIIVI	Min	Max
Α	9.8	10.4	E	3.75	3.95	I	4.38	4.61
В	2.65	3.1	F	14.8	16.1	J	1.15	1.36
С	2.8	4.2	G	13.05	13.6	K	5.85	6.82
D	0.7	0.92	Н	2.4	2.7	L	2.35	2.75
М	0.35	0.65	N	1.18	1.42		•	•



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